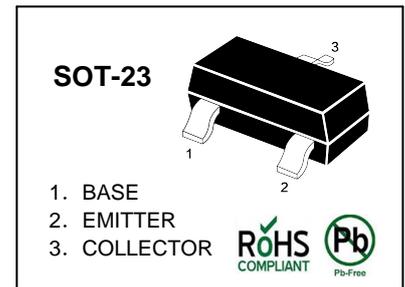


PNP Silicon Epitaxial Planar Transistor

The transistor is subdivided into three groups Q, R and S according to its DC current gain.

On special request, these transistors can be manufactured in different pin configurations.



Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

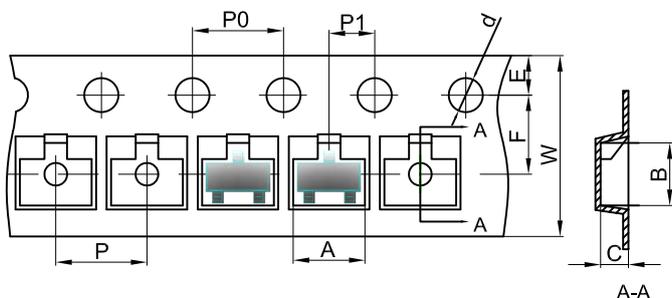
Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	60	V
Collector Current	$-I_C$	150	mA
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_s	-55 to +150	$^\circ\text{C}$

Characteristics at $T_{amb}=25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE}=6\text{V}$, $-I_C=1\text{mA}$	Q h_{FE}	120	270	-
	R h_{FE}	180	390	-
	S h_{FE}	270	560	-
Collector Cutoff Current at $-V_{CB}=60\text{V}$	$-I_{CBO}$	-	0.1	μA
Emitter Cutoff Current at $-V_{EB}=6\text{V}$	$-I_{EBO}$	-	0.1	μA
Collector Saturation Voltage at $-I_C=50\text{mA}$, $-I_B=5\text{mA}$	$-V_{CE(sat)}$	-	0.5	V
Collector Base Breakdown Voltage at $-I_C=50\mu\text{A}$	$-V_{(BR)CBO}$	60	-	V
Collector Emitter Breakdown Voltage at $-I_C=1\text{mA}$	$-V_{(BR)CEO}$	50	-	V
Emitter Base Breakdown Voltage at $-I_E=50\mu\text{A}$	$-V_{(BR)EBO}$	6	-	V
Transition Frequency at $-V_{CE}=12\text{V}$, $-I_C=2\text{mA}$, $f=30\text{MHz}$	f_T	120	-	MHz

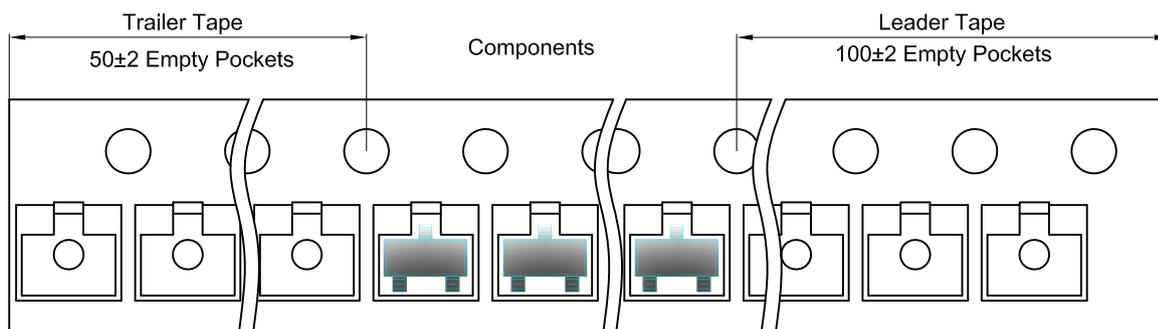
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

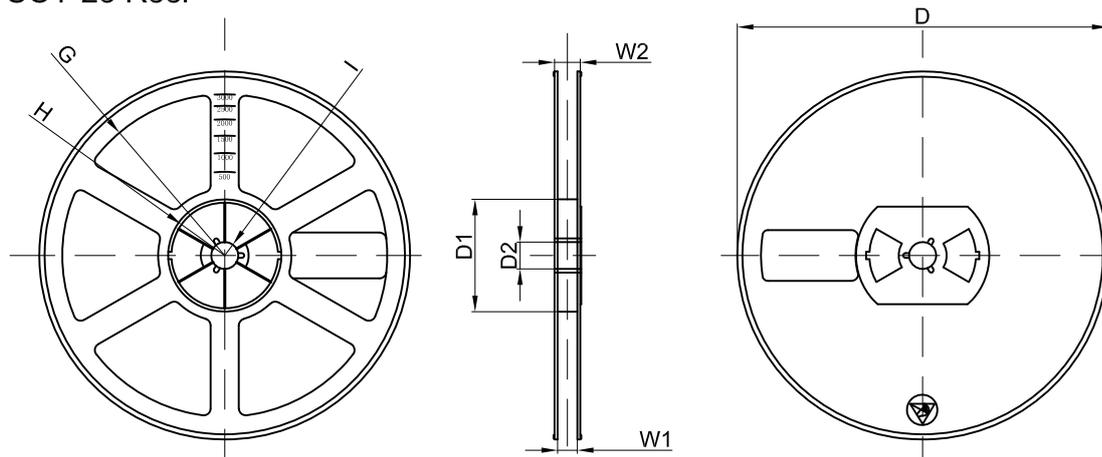


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer

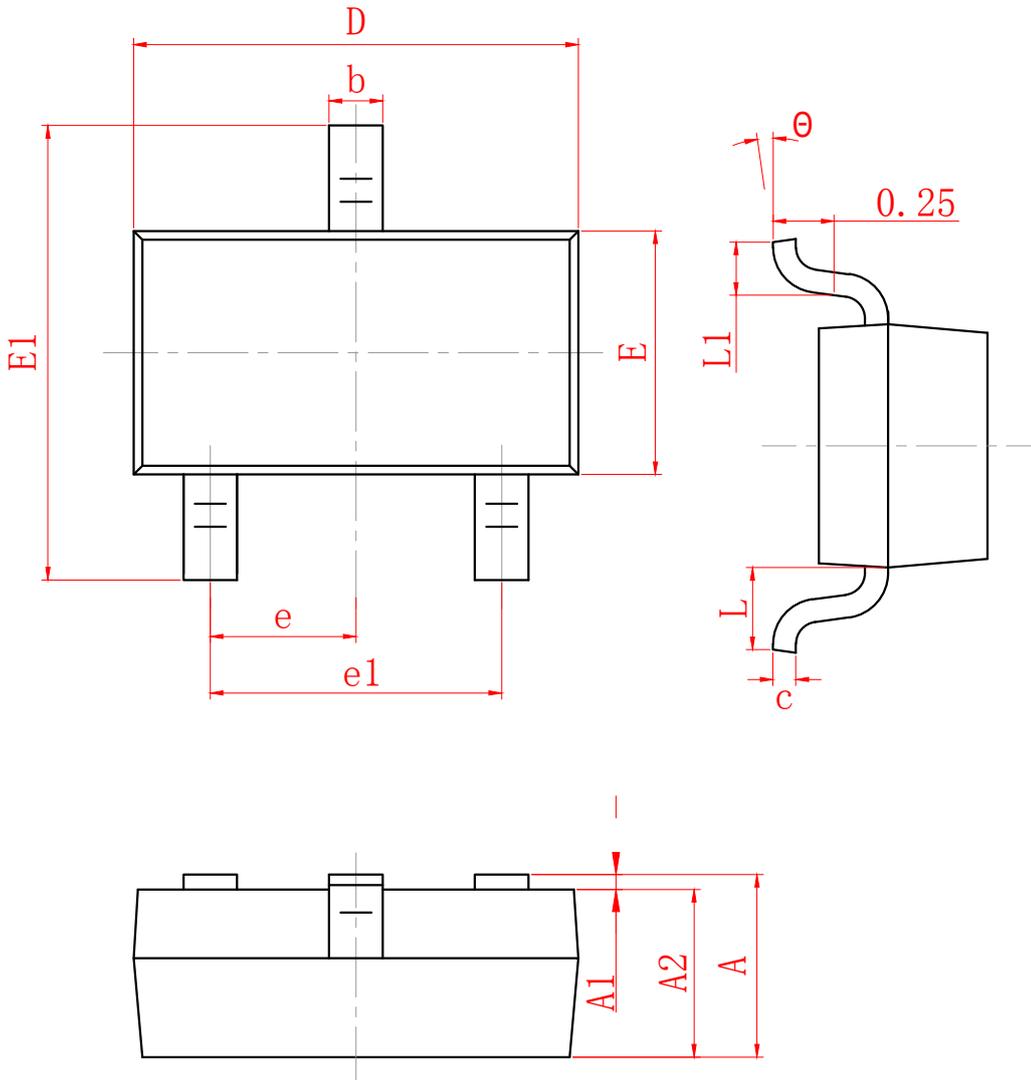


SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	



SYMBOL	MILLIMETER	
	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950 TYP	
e1	1.800	2.000
L	0.550 REF	
L1	0.300	0.500
θ	0°	8°

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